

EMD1S THRU EMD4S

SINGLE-PHASE GLASS PASSIVATED MINI SUPER FAST SURFACE MOUNT BRIDGE RECTIFIER VOLTAGE RANGE 50 to 200 Volts CURRENT 0.5 Ampere

FEATURES

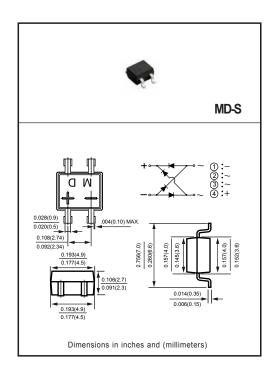
- * Surge overload rating 20 amperes peak
- * Ideal for printed circuit board
- * Reliable low cost construction utilizing molded
- * Glass passivated device
- * Polarity symbols molded on body
- * Mounting position: Any
- * Weight: 0.5 gram

MECHANICAL DATA

* Epoxy: Device has UL flammability classification 94V-O

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 $^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	EMD1S	EMD2S	EMD3S	EMD4S	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	150	200	Volts
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	105	140	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	Volts
Maximum Average Forward Output Current at T_A =30°C -on glass-epoxy P.C.B. (Note 2) -on aluminum substrate (Note 3)	Io	0.5 0.8				
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	20				Amps
Typical Junction Capacitance (Note 4)	CJ	15			pF	
Operating and Storage Temperature Range	TJ,TSTG	-55 to + 150				٥C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

	,						
CHARACTERISTICS		SYMBOL	EMD1S	EMD2S	EMD3S	EMD4S	UNITS
Maximum Forward Voltage Drop per Bridge		V _F	1.05				Volts
Element at 0.5A DC							
Maximum Reverse Current at Rated	@T _A = 25°C	l_	10				μAmps
DC Blocking Voltage per element	@T _A = 125°C	I _R	0.5				mAmps
Maximum Reverse Recovery Time (Note 5)		trr	50				nS

Note: 1."Fully ROHS compliant","100% Sn plating(Pb-free).

- 2. On glass-epoxy P.C.B. mounted on 0.05 X 0.05" (1.3 X 1.3mm) pads.
- 3. On aluminum substrate P.C.B. with an area of 0.8 X 0.8 X 0.25" (20 X 20 X 6.4mm) mounted on 0.05 X 0.05" (1.27 X 1.27mm) solder pad.
- Measure at 1MHz and applied reverse voltage of 4.0 volts.
- 5. Test Condition : I_F=0.5A, I_R= -1.0A,I_{RR}= -0.25A.

2007-08

RATING AND CHARACTERISTICS CURVES (EMD1S THRU EMD4S)

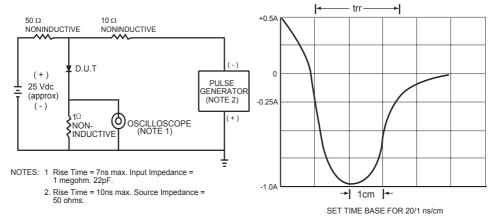


FIG.1 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

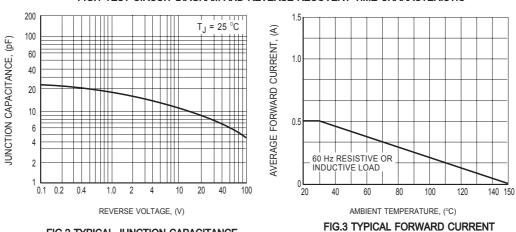


FIG.2 TYPICAL JUNCTION CAPACITANCE

DERATING CURVE

RATING AND CHARACTERISTICS CURVES (EMD1S THRU EMD4S)

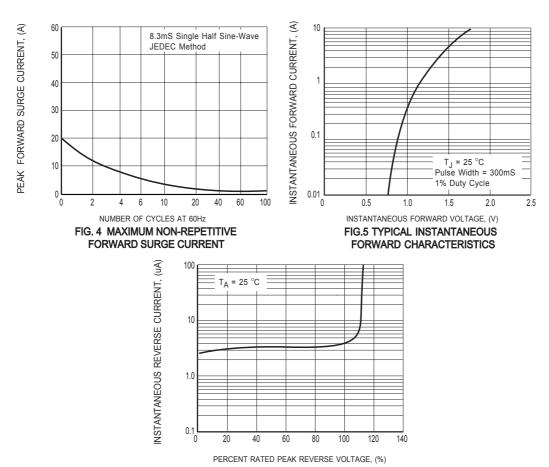
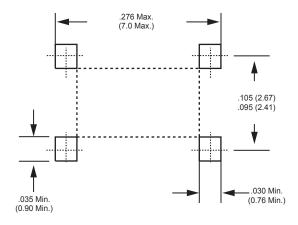


FIG.6 TYPICAL REVERSE CHARACTERISTICS



Mounting Pad Layout



Dimensions in inches and (millimeters)



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